

XR1009, XR2009 0.2mA, 35MHz Rail-to-Rail Amplifiers

General Description

The XR1009 (single) and XR2009 (dual) are ultra-low power, low cost, voltage feedback amplifiers. These amplifiers use only 208μ A of supply current and are designed to operate from a supply range of 2.5V to 5.5V (±1.25 to ±2.75). The input voltage range extends 300mV below the negative rail and 1.2V below the positive rail.

The XR1009 and XR2009 offer superior dynamic performance with a 35MHz small signal bandwidth and $27V/\mu s$ slew rate. The combination of low power, high bandwidth, and rail-to-rail performance make the XR1009 and XR2009 well suited for battery-powered communication/ computing systems.

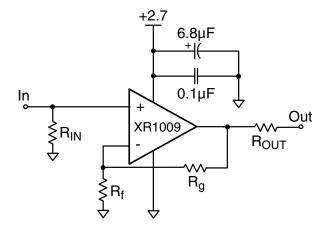
FEATURES

- 208µA supply current
- 35MHz bandwidth
- Input voltage range with 5V supply: -0.3V to 3.8V
- Output voltage range with 5V supply: 0.08V to 4.88V
- 27V/µs slew rate
- 21nV/JHz input voltage noise
- 13mA linear output current
- Fully specified at 2.7V and 5V supplies
- Replaces MAX4281

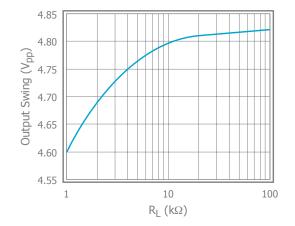
APPLICATIONS

- Portable/battery-powered applications
- Mobile communications, cell phones,
- pagers
- ADC buffer
- Active filters
- Portable test instruments
- Signal conditioning
- Medical equipment
- Portable medical instrumentation
- Interactive whiteboards

Frequency Response



Output Swing vs. RL



Absolute Maximum Ratings

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

V _S	
V _{IN}	
Continuous Output Current	30mA to +30mA

Operating Conditions

Supply Voltage Range	2.5 to 5.5V
Operating Temperature Range	40°C to 125°C
Junction Temperature	150°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering, 10s)	260°C

Package Thermal Resistance

θ _{JA} (TSOT23-5)	215°C/W
θ _{JA} (SOIC-8)	150°C/W
θ _{JA} (MSOP-8)	200°C/W
Package thermal resistance (θ_{JA}), JEDEC s test boards, still air.	standard, multi-layer

ESD Protection

XR1009 (HBM)	2kV
XR2009 (HBM)	2.5kV
ESD Rating for HBM (Human Body Model).	

Electrical Characteristics at +2.7V

 T_A = 25°C, V_S = +2.7V, R_f = R_g = 2.5k $\Omega,~R_L$ = 2k Ω to $V_S/2;~G$ = 2; unless otherwise noted.

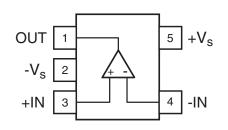
Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency I	Domain Response					
UGBW _{SS}	Unity Gain -3dB Bandwidth	$G = +1, V_{OUT} = 0.05V_{pp}, R_f = 0$		28		MHz
BW _{SS}	-3dB Bandwidth	$G = +2, V_{OUT} < 0.2V_{pp}$		15		MHz
BW _{LS}	Large Signal Bandwidth	$G = +2, V_{OUT} = 2V_{pp}$		7		MHz
GBWP	Gain Bandwidth Product	$G = +11, V_{OUT} = 0.2V_{pp}$		16		MHz
Time Doma	in Response					
t _R , t _F	Rise and Fall Time	V _{OUT} = 0.2V step; (10% to 90%)		16		ns
t _S	Settling Time to 0.1%	V _{OUT} = 1V step		140		ns
OS	Overshoot	V _{OUT} = 1V step		1		%
SR	Slew Rate	G = -1, 2V step		20		V/µs
Distortion/N	loise Response					
HD2	2nd Harmonic Distortion	100kHz, V _{OUT} = 1 V _{pp}		-85		dBc
HD3	3rd Harmonic Distortion	100kHz, V _{OUT} = 1 V _{pp}		-63		dBc
THD	Total Harmonic Distortion	100kHz, V _{OUT} = 1 V _{pp}		62		dB
e _n	Input Voltage Noise	>10kHz		23		nV/√H
XTALK	Crosstalk	100kHz, V _{OUT} = 0.2 V _{pp}		98		dB
DC Perform	ance		1			
V _{IO}	Input Offset Voltage			0.8		mV
d _{VIO}	Average Drift			11		μV/°C
I _B	Input Bias Current			0.37		μA
dl _B	Average Drift			1		nA/°C
I _{OS}	Input Offset Current			8		nA
PSRR	Power Supply Rejection Ratio	DC	56	60		dB
A _{OL}	Open Loop Gain	$V_{OUT} = V_S / 2$		65		dB
I _S	Supply Current	per channel		185		μA
Input Chara	cteristics					
R _{IN}	Input Resistance	Non-inverting		>10		ΜΩ
C _{IN}	Input Capacitance			1.4		pF
CMIR	Common Mode Input Range			-0.3 to 1.5		V
CMRR	Common Mode Rejection Ratio	DC, $V_{CM} = 0V$ to $V_{S} - 1.5V$		92		dB
Output Cha	racteristics					
		R_L = 2k\Omega to V_S / 2		0.08 to 2.6		V
V _{OUT}	Output Voltage Swing	$R_L = 10 k\Omega$ to $V_S / 2$		0.06 to 2.62		V
I _{OUT}	Output Current			±8		mA
I _{SC}	Short Circuit Current			±12.5		mA

Electrical Characteristics at +5V

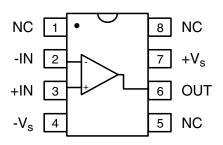
 T_A = 25°C, V_S = +5V, R_f = R_g = 2.5k\Omega, R_L = 2k\Omega to $V_S/2;$ G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency [Domain Response					
UGBW _{SS}	Unity Gain -3dB Bandwidth	$G = +1, V_{OUT} = 0.05V_{pp}, R_f = 0$		35		MHz
BW _{SS}	-3dB Bandwidth	$G = +2, V_{OUT} < 0.2V_{pp}$		18		MHz
BW _{LS}	Large Signal Bandwidth	$G = +2, V_{OUT} = 2V_{pp}$		8		MHz
GBWP	Gain Bandwidth Product	$G = +11, V_{OUT} = 0.2V_{pp}$		20		MHz
Time Doma	in Response		·			
t _R , t _F	Rise and Fall Time	V _{OUT} = 0.2V step; (10% to 90%)		13		ns
ts	Settling Time to 0.1%	V _{OUT} = 1V step		140		ns
OS	Overshoot	V _{OUT} = 1V step		1		%
SR	Slew Rate	G = -1, 2V step		27		V/µs
Distortion/N	loise Response					
HD2	2nd Harmonic Distortion	100kHz, $V_{OUT} = 2V_{pp}$		-78		dBc
HD3	3rd Harmonic Distortion	100 kHz, V _{OUT} = $2V_{pp}$		-66		dBc
THD	Total Harmonic Distortion	100kHz, $V_{OUT} = 2V_{pp}$		65		dB
en	Input Voltage Noise	>10kHz		21		nV/√Hz
XTALK	Crosstalk	100kHz, $V_{OUT} = 0.2V_{pp}$		98		dB
DC Perform	ance		·			
V _{IO}	Input Offset Voltage		-5	-1.5	5	mV
d _{VIO}	Average Drift			20		μV/°C
I _B	Input Bias Current		-1.3	0.37	1.3	μA
dl _B	Average Drift			1		nA/°C
I _{OS}	Input Offset Current			7	130	nA
PSRR	Power Supply Rejection Ratio	DC	56	60		dB
A _{OL}	Open Loop Gain	$V_{OUT} = V_S / 2$	56	62		dB
I _S	Supply Current	per channel		208	260	μA
Input Chara	cteristics					
R _{IN}	Input Resistance	Non-inverting		>10		ΜΩ
C _{IN}	Input Capacitance			1.2		pF
CMIR	Common Mode Input Range			-0.3 to 3.8		V
CMRR	Common Mode Rejection Ratio	DC, $V_{CM} = 0V$ to $V_S - 1.5V$	65	95		dB
Output Cha	racteristics					
		R_L = 2k\Omega to V_S / 2	0.2 to 4.7	0.1 to 4.8		V
V _{OUT}	Output Voltage Swing	$R_L = 10 k\Omega$ to $V_S / 2$		0.08 to 4.88		V
I _{OUT}	Output Current			±8.5		mA
I _{SC}	Short Circuit Current			±13		mA

XR1009 Pin Configurations



SOIC-8



XR1009 Pin Assignments

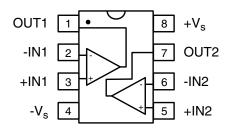
TSOT-5

Pin No.	Pin Name	Description
1	OUT	Output
2	-V _S	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+V _S	Positive supply

SOIC-8

Pin No.	Pin Name	Description
1	NC	No Connect
2	-IN	Negative input
3	+IN	Positive input
4	-V _S	Negative supply
5	NC	No Connect
6	OUT	Output
7	+V _S	Positive supply
8	NC	No Connect

XR2009 Pin Configuration SOIC-8 / MSOP-8



XR2009 Pin Assignments

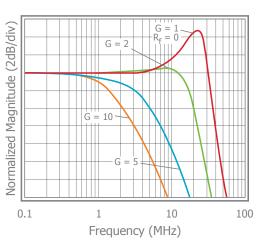
SOIC-8 / MSOP-8

Pin No.	Pin Name	Description	
1	OUT1	Output, channel 1	
2	-IN1	Negative input, channel 1	
3	+IN1	Positive input, channel 1	
4	-V _S	Negative supply	
5	+IN2	Positive input, channel 2	
6	-IN2	Negative input, channel 2	
7	OUT2	Output, channel 2	
8	+V _S	Positive supply	

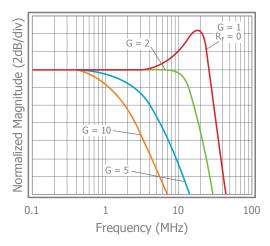
Typical Performance Characteristics

 $T_A = 25^{\circ}C$, $V_S = +5V$, $R_f = R_g = 2.5k\Omega$, $R_L = 2k\Omega$ to $V_S/2$; G = 2; unless otherwise noted.

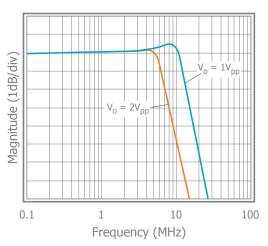
Non-Inverting Frequency Response at $V_S = 5V$



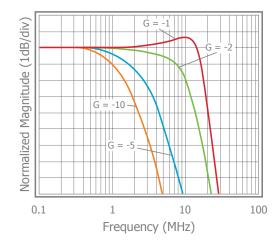
Non-Inverting Frequency Response at V_S = 2.7V



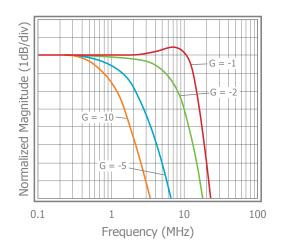
Frequency Response vs. V_{OUT}



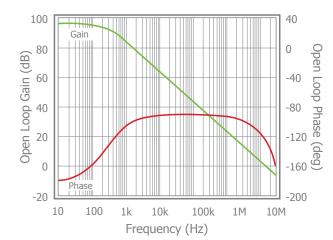
Inverting Frequency Response at $V_S = 5V$



Inverting Frequency Response at $V_S = 2.7V$



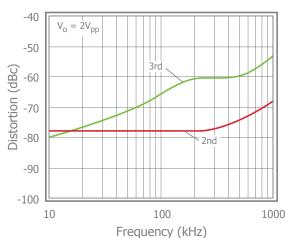
Open Loop Gain & Phase vs. Frequency



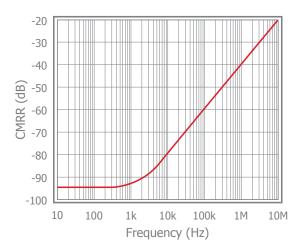
Typical Performance Characteristics

 T_A = 25°C, V_S = +5V, R_f = R_g = 2.5k\Omega, R_L = 2k\Omega to $V_S/2;$ G = 2; unless otherwise noted.

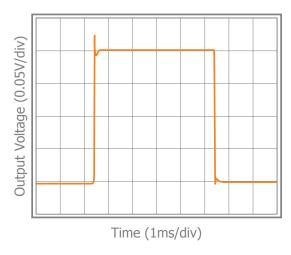
2nd & 3rd Harmonic Distortion at $V_{S}\,{=}\,5V$



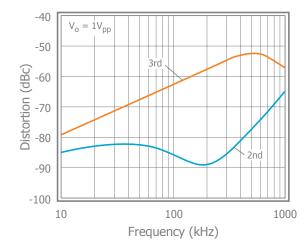




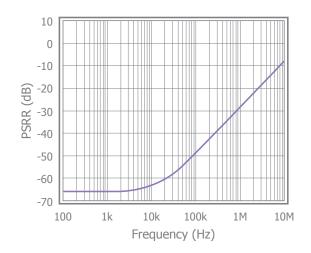
Small Signal Pulse Response



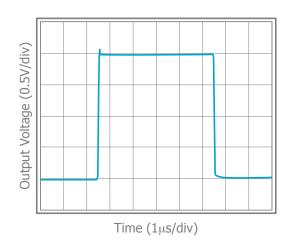




PSRR





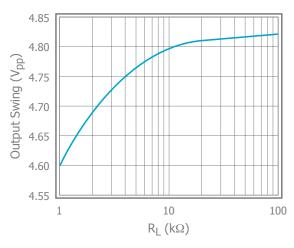


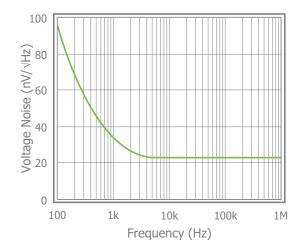
Typical Performance Characteristics

 $T_A = 25^{\circ}C$, $V_S = +5V$, $R_f = R_g = 2.5k\Omega$, $R_L = 2k\Omega$ to $V_S/2$; G = 2; unless otherwise noted.

Output Swing vs. RL







Application Information

General Description

The XR1009 and XR2009 are a single supply, general purpose, voltage-feedback amplifiers fabricated on a complementary bipolar process. The XR1009 offers 35MHz unity gain bandwidth, $27V/\mu s$ slew rate, and only $208\mu A$ supply current. It features a rail-to-rail output stage and is unity gain stable.

The design utilizes a patent pending topology that provides increased slew rate performance. The common mode input range extends to 300mV below ground and to 1.2V below Vs. Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct. The output will stay at the rail during this overdrive condition.

The design uses a Darlington output stage. The output stage is short circuit protected and offers "soft" saturation protection that improves recovery time.

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations. Figure 4 shows the typical non-inverting gain circuit for single supply applications.

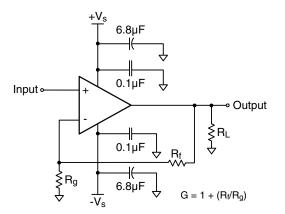
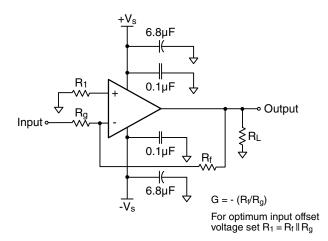


Figure 1: Typical Non-Inverting Gain Circuit





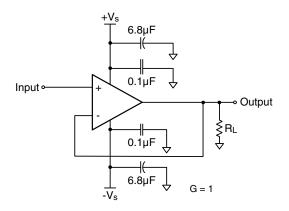


Figure 3: Unity Gain Circuit

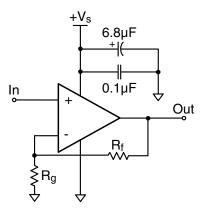


Figure 4: Single Supply Non-Inverting Gain Circuit

Power Dissipation

Power dissipation should not be a factor when operating under the stated $2k\Omega$ load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta_{JA} (θ_{JA}) is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\theta_{JA} \times P_D)$$

Where $\mathsf{T}_{\mathsf{Ambient}}$ is the temperature of the working environment.

In order to determine P_D , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{supply} - P_{load}$$

Supply power is calculated by the standard power equation.

$$P_{supply} = V_{supply} \times I_{RMSsupply}$$
$$V_{supply} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{load})_{RMS^2})/Rload_{eff}$$

The effective load resistor ($Rload_{eff}$) will need to include the effect of the feedback network. For instance,

Rload_{eff} in Figure 3 would be calculated as:

$$R_L \parallel (R_f + R_g)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, P_D can be found from

$$P_D = P_{Quiescent} + P_{Dynamic} - P_{load}$$

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{supply} . Load power can be calculated as above with the desired signal amplitudes using:

$$(V_{load})_{RMS} = V_{peak} / \sqrt{2}$$

$$(I_{load})_{RMS} = (V_{load})_{RMS} / Rload_{eff}$$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

 $P_{Dynamic} = (V_{S+} - V_{load})_{RMS} \times (I_{load})_{RMS}$

Assuming the load is referenced in the middle of the power rails or $V_{supply}/2$.

The XR1009 is short circuit protected. However, this may not guarantee that the maximum junction temperature (+150°C) is not exceeded under all conditions. Figure 5 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

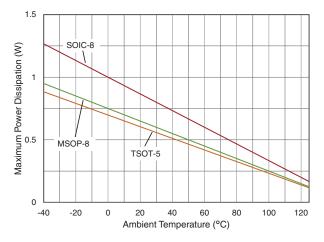


Figure 5. Maximum Power Derating

Driving Capacitive Loads

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 6.

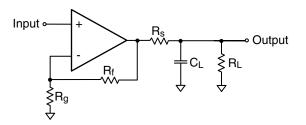


Figure 6. Addition of R_S for Driving Capacitive Loads

Overdrive Recovery

For an amplifier, an overdrive condition occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the ranges are exceeded. The XR1009, and XR2009 will typically recover in less than 20ns from an overdrive condition.

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Exar has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.1µF ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board #	Products
CEB002	XR1009 in TSOT
CEB003	XR1009 in SOIC
CEB006	XR2009 in SOIC
CEB010	XR2009 in MSOP

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 9-18 These evaluation boards are built for dualsupply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -V $_{\rm S}$ to ground.
- 2. Use C3 and C4, if the -V_S pin of the amplifier is not directly connected to the ground plane.

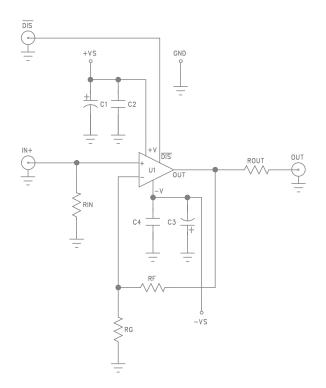


Figure 9. CEB002 & CEB003 Schematic

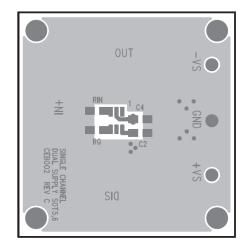


Figure 10. CEB002 Top View

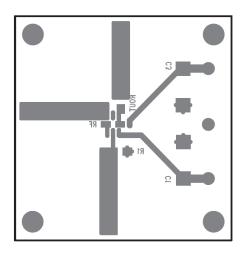


Figure 11. CEB002 Bottom View

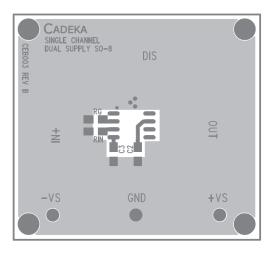


Figure 12. CEB003 Top View

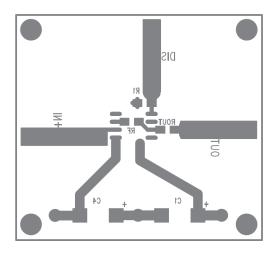


Figure 13. CEB003 Bottom View

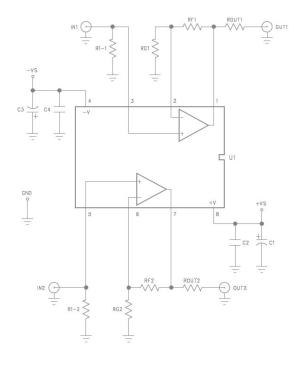


Figure 14. CEB006 & CEB010 Schematic

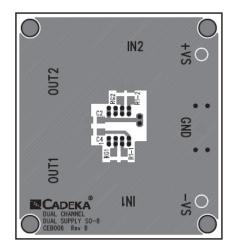


Figure 15. CEB006 Top View

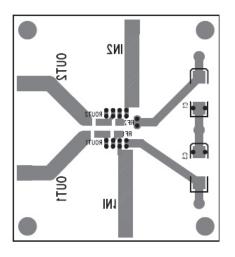


Figure 16. CEB006 Bottom View

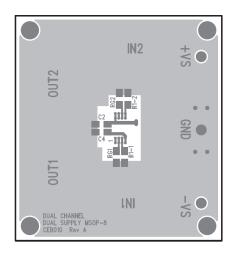


Figure 17. CEB010 Top View

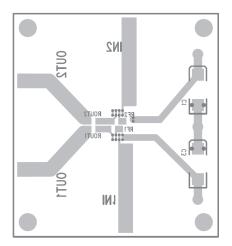
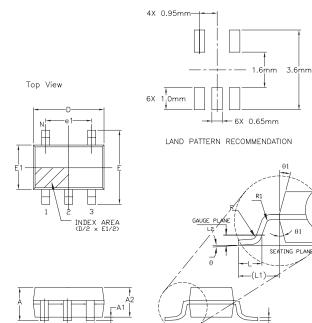


Figure 18. CEB010 Bottom View

Mechanical Dimensions

TSOT-5 Package



5 Pin TSOT (OPTION 2)							
SYMBOLS	DIMENSION IN MM (Control Unit)		DIMENSION IN INCH (Reference Unit)				
	MIN	NOM	MAX	MIN	NOM	MAX	
A	0.75	—	0.80	0.030	—	0.031	
A1	0.00	—	0.05	0.000	-	0.002	
A2	0.70	0.75	0.78	0.028	0.030	0.031	
b	0.35	—	0.50	0.012	—	0.020	
с	0.10	—	0.20	0.003	—	0.008	
D	2	2.90 BS	SC SC	0.114 BSC			
E	2	2.80 BS	SC	0.110 BSC			
E1	1	.60 BS	SC	0.063 BSC			
е	().95 BS	SC	0.038 BSC			
e1	1	.90 BS	SC	0.075 BSC			
L	0.37	0.45	0.60	0.012	0.018	0.024	
L1	(D.60 RE	F	0	.024 RE	F	
L2	().25 BS	SC	0	.010 BS	SC	
R	0.10	-	-	0.004	-	-	
R1	0.10	_	0.25	0.004	_	0.010	
θ	0*	4*	8*	0*	4.	8*	
θ1	4'	10*	12*	4'	10*	12*	
N	5				5		

Side View

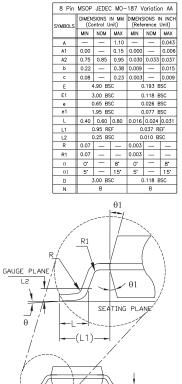
Front View

θ1

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MSOP-8 Package

Top View \vdash É 1 2 З INDEX AREA

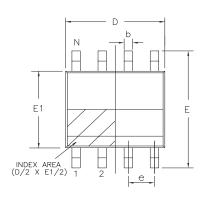


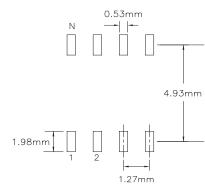


Side View

Front View 14 / 16

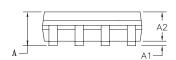
SOIC-8 Package

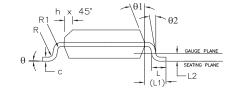




RECOMMENDED PCB LAND PATTERN

Top View





Front View

Side View

8 Pin SOICN JEDEC MS-012 Variation AA						
SYMBOLS		DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)	
	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.35		1.75	0.053	_	0.069
A1	0.10	-	0.25	0.004	_	0.010
A2	1.25		1.65	0.049	-	0.065
b	0.31	_	0.51	0.012	-	0.020
с	0.17	_	0.25	0.007	-	0.010
E	(5.00 BSC	>	0.236 BSC		
E1		3.90 BS0	2	0.154 BSC		
е		1.27 BS0	2	0.050 BSC		
h	0.25	_	0.50	0.010	_	0.020
L	0.40	-	1.27	0.016	_	0.050
L1		1.04 REF		0.041 REF		
L2		0.25 BS0	2	0	.010 BS	2
R	0.07	-	-	0.003	_	-
R1	0.07	_	-	0.003	_	-
θ	0.	_	8'	0.	_	8'
01	5'	—	15'	5'	-	15'
02	0.	_	-	0.	_	-
D	4.90 BSC			0.193 BSC		
N		8			8	



Ordering Information

Part Number	Package	Green	Operating Temperature Range	Packaging Quantity	Marking		
XR1009 Ordering Information							
XR1009IST5X	TSOT-5	Yes	-40°C to +125°C	2.5k Tape & Reel	UC		
XR1009IST5MTR	TSOT-5	Yes	-40°C to +125°C	250 Tape & Reel	UC		
XR1009IST5EVB	Evaluation Board	N/A	N/A	N/A	N/A		
XR1009ISO8X	SOIC-8	Yes	-40°C to +125°C	2.5k Tape & Reel	XR1009		
XR1009ISO8MTR	SOIC-8	Yes	-40°C to +125°C	250 Tape & Reel	XR1009		
XR1009ISO8EVB	Evaluation Board	N/A	N/A	N/A	N/A		
XR2009 Ordering Inform	nation						
XR2009ISO8X	SOIC-8	Yes	-40°C to +125°C	2.5k Tape & Reel	XR2009		
XR2009ISO8MTR	SOIC-8	Yes	-40°C to +125°C	250 Tape & Reel	XR2009		
XR2009ISO8EVB	Evaluation Board	N/A	N/A	N/A	N/A		
XR2009IMP8X	MSOP-8	Yes	-40°C to +125°C	2.5k Tape & Reel	2009		
XR2009IMP8MTR	MSOP-8 Yes		-40°C to +125°C	250 Tape & Reel	2009		
XR2009IMP8EVB	Evaluation Board	N/A	N/A	N/A	N/A		

Moisture sensitivity level for all parts is MSL-1.

Revision History

Revision	Date	Description	
1A	June 2014	Initial Release [ECN 1426-10 06/24/14]	
1B	Sept 2014	Added XR1009 ESD, increased operating temperature range, updated package outline drawings, and removed Preliminary note on XR1009. [ECN 1436-03 I 09/04/14]	

For Further Assistance:

Email: CustomerSupport@exar.com or HPATechSupport@exar.com

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Exar Corporation Headquarters and Sales Offices

 48760 Kato Road
 Tel.: +1 (510) 668-7000

 Fremont, CA 94538 - USA
 Fax: +1 (510) 668-7001

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